## إنه وإنتاق الأنتاق عليه مكتب والمستقل والمستقل والمستقل والمستقل والمستقل المستقل والمستقل وا

## PROCESS FOR FABRICATING THIN-FILM DEVICE AND THIN-FILM DEVICE

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## ABSTRACT OF THE DISCLOSURE

In a process for producing a thin-film device, a conducting layer composed of an anodically oxidizable metal is formed on a substrate and is etched to form gate bus lines and gate electrode having upper surfaces parallel to the substrate and inclined side surfaces. The gate bus lines and the gate electrodes are anodically oxidized, so that they include inner conducting portions and outer insulating oxide films covering the inner conducting portions. The outer insulating films prevent the bus lines from short circuiting, and the inclined side surfaces of the bus lines makes it possible to fabricate a dense wiring arrangement.